CLOCK I	
WAIT - 2	39 XTAL
CLEAR 3	38 DWA IN
0 - 4	37 DHA OUT
SC 1 5	36 INTERRUPT
sco — 6	35 NWR
MRD 7	34 TPA
eus 7 — e	33- TP8
BUS 6 - 9	32 MA7
BUS 5 10	31 MA6
BUS 4	30- NA5
BUS 3 12	29 MA4
BUS 2	28 MA3
BUS I	27 MA2
BUS 0 15	26 MAI
	25 MAO
N2 17	24 EFT
NI	23 EF2
NO 19	22
VSS -20	21 EF4
TOP	VIEW
	9265 274678

CMOS 8-Bit Microprocessor

- Features:
 - Minimum instruction fetch-execute time of 5 μs or 7.5 μs at V_{DD} = 5 V; 2.5 μs or 3.75 μs at V_{DD} = 10 V
- Any combination of standard RAM and ROM up to 65,536 bytes
- Operates with slow memories, up to 1 µs access time at f_{cL} = 4 MHz
- 8-bit parallel organization with bidirectional data bus and multiplexed address bus
- 16 x 16 matrix of registers for use as multiple program counters, data pointers, or data registers
- On-chip DMA, interrupt, and flag inputs
- Programmable single-bit output port
- 91 easy-to-use instructions

TERMINAL ASSIGNMENT

The RCA-CDP1802A LSI CMOS 8-bit register-oriented central-processing unit (CPU) is designed for use as a general-purpose computing or control element in a wide range of stored-program systems or products.

The CDP1802A includes all of the circuits required for fetching, interpreting, and executing instructions which have been stored in standard types of memories. Extensive input/output (I/O) control features are also provided to facilitate system design.

The 1800 series architecture is designed with emphasis on the total microcomputer system as an integral entity so that systems having maximum flexibility and minimum cost can be realized. The 1800 series CPU also provides a synchronous interface to memories and external controllers for I/O devices, and minimizes the cost of interface controllers. Further, the I/O interface is capable of supporting devices operating in polled, interrupt-driven, or direct memory-access modes.

The CDP1802A and CDP1802AC are functionally identical. They differ in that the CDP1802A has a recommended operating voltage range of 4 to 10.5 volts, and the CDP1802AC a recommended operating voltage range of 4 to 6.5 volts.

These types are supplied in 40-lead dual-in-line sidebrazed ceramic packages (D suffix), 40-lead dual-in-line plastic packages (E suffix) and 44-lead plastic chip-carrier (PCC) package (Q suffix). The CDP1802AC is also available in chip form (H suffix).

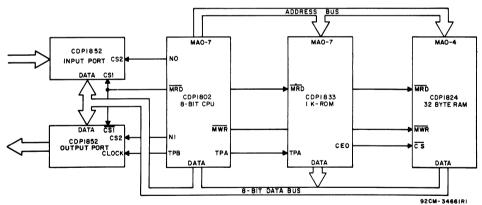


Fig. 1 - Typical CDP1802A small microprocessor system.

File Number 1305

MAXIMUM RATINGS, Absolute-Maximum Values:	
DC SUPPLY-VOLTAGE RANGE, (V _{DD}).	
(All voltages referenced to VSS terminal)	
CDP1802A	–0.5 to +11 V
CDP1802AC	0.5 to +7 V
DC INPUT CURRENT, ANY ONE INPUT	±10 mA
POWER DISSIPATION PER PACKAGE (PD):	
For T _A =-40 to +60°C (PACKAGE TYPE E)	
For T _A =+60 to +85°C (PACKAGE TYPE E)	Derate Linearly at 12 mW/°C to 200 mW
For T _A =-55 to +100°C (PACKAGE TYPE D)	
	Derate Linearly at 12 mW/°C to 200 mW
For T _A = -40°C to +85°C (PACKAGE TYPE Q) *	
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
FOR T _A =FULL PACKAGE-TEMPERATURE RANGE	
OPERATING-TEMPERATURE RANGE (TA)	
PACKAGE TYPE E and Q	
STORAGE TEMPERATURE RANGE (T _{stg})	
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 \pm 1/32 in (1.59 \pm 0 79 mm) from case for 10 s max	+265°C

* Printed-circuit board mount: 57 mm x 57 mm minimum area x 1.6 mm thick G10 epoxy glass, or equivalent.

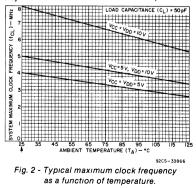
OPERATING CONDITIONS at TA=-40°C to +85°C

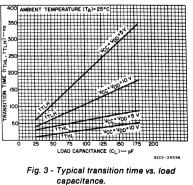
For maximum reliability, operating conditions should be selected so that operation is always within the following ranges:

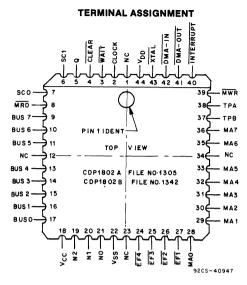
	COND	TIONS					
CHARACTERISTIC	Vcc1	VDD	CDP1802A		CDP1802AC		UNITS
	(V)	(V)	Min.	Max.	Min.	Max.	
DC Operating Voltage Range	_	_	4	10.5	4	6.5	v
Input Voltage Range	-	_	VSS	VDD	VSS	VDD	v
Maximum Clock Input Rise or Fall Time, t _r ,t _f	4 to 10.5	4 to 10.5	_	1	-	1	
	5	5	5	-	5	-	
Minimum Instruction Time ²	5	10	4	_	-	_	μs
	10	10	2.5	-	_	-	
	5	5	_	400		400	KBytes
Maximum DMA Transfer	5	10	_	500	-	-	per
Rate	10	10		800		-	second
Maximum Clock Input	5	5	DC	3.2	DC	3.2	
Frequency, f _{CL} , Load	5	10	DC	4		-	MHz
Capacitance (CL)=50 pF	10	10	DC	6.4	-	-	

1VCC must never exceed VDD.

²Equals 2 machine cycles—one Fetch and one Execute operation for all instructions except Long Branch and Long Skip, which require 3 machine cycles—one Fetch and two Execute operations







Plastic Chip-Carrier (PCC) Package

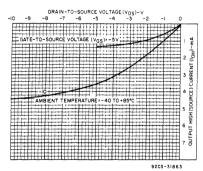


Fig. 4 · Minimum output high (source) current characteristics.

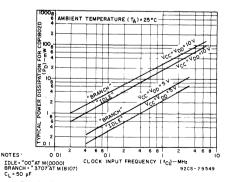


Fig. 6 - Typical power dissipation as a function of clock frequency for BRANCH instruction and IDLE instruction

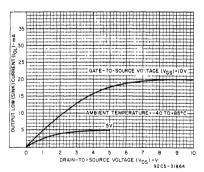


Fig. 5 - Minimum output low (sink) current characteristics.

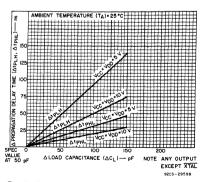


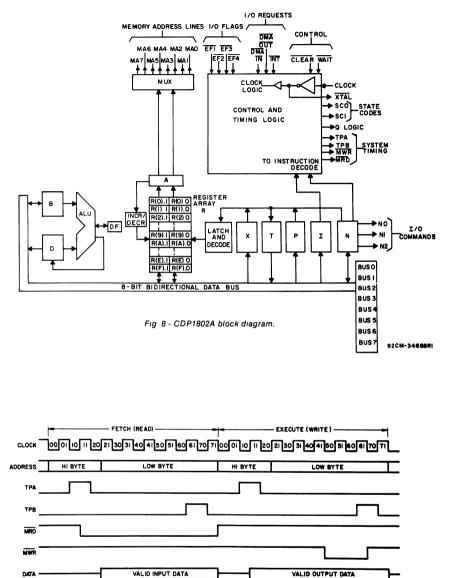
Fig 7 - Typical change in propagation delay as a function of a change in load capacitance.

STATIC ELECTRICAL CHARACTERISTICS at TA=-40 to +85° C, except as noted.

		CONDITIONS								
CHARACTERISTIC	Vout	VOUT VIN			CDP1802A		CDP1802AC		UNITS	
	(V)	(V)	(V)	Min.	Тур.•	Max.	Min.	Тур.•	Max.	
Quiescent Device Current IDD	_	_	5 10	_	01	50 200	-	1	200 —	μA
Output Low Drive (Sink)										
Current IOL	0.4	0,5	5	1.1	2.2	_	1.1	2.2	_	
(Except XTAL)	05	0,10	10	22	4.4	_	-	—	-	mA
XTAL IOL	0.4	5	5	170	350		170	350	_	μA
Output High Drive (Source)										
Current IOH	4.6	0,5	5	-0 27	-0 55	-	-0.27	-0.55	_	m 4
(Except XTAL)	9.5	0,10	10	-0 55	-1.1	_	—	_	_	mA
XTAL ^I OH	4.6	0	5	-125	-250	—	-125	-250	_	μA
Output Voltage		0,5	5		0	0.1	—	0	0.1	
Low-Level VOL	_	0,10	10	_	0	0.1	-	_	_	
Output Voltage	_	0,5	5	4 9	5	_	4.9	5		
High Level VOH	_	0,10	10	9.9	10	_	-	_	_	
Input Low Voltage VIL	0.5,4.5		5		—	1.5	_	_	1.5	
	0.5, 4.5	—	5,10	-	_	1	-	_	_	
	1,9	—	10	_	_	3	—	_	_	V
Input High Voltage VIH	0.5,4.5		5	3.5	-	—	3.5	—	_	
	0.5,4.5		5,10	4	—		—			
	1,9	-	10	7	-	—	_	_	—	
CLEAR Input Voltage VH		_	5	0.4	0.5	—	0.4	0.5		
Schmitt Hysteresis			5,10	0.3	0.4	—	-	_		
		—	10	1.5	2	-	-	_		
Input Leakage Current IIN	Any	0,5	5	_	±10-4	±1	-	±10-4	±1	
	Input	0,10	10		±10-4	±1			_	μA
3-State Output Leakage	0,5	0,5	5		±10-4	±1	-	±10 ⁻⁴	±1	μΑ
Current IOUT	0,10	0,10	10	—	±10-4	±1	—	—	—	
Operating Current, I _{DD1} ∆ f=3.2 MHz	_	_	5	_	2	4	_	2	4	mA
Minimum Data Retention			.							
Voltage VDR		VDD=VDR		_	2	2.4	_	2	2.4	v
Data Retention Current IDR		V _{DD} =2.4 V			0.05		_	0.5	_	μA
Input Capacitance CIN				_	5	7.5	_	5	7.5	· · · · · · · · · · · · · · · · · · ·
Output Capacitance COUT				- 1	10	15	-	10	15	pF

 $^{\bullet}\textsc{Typical}$ values are for $\textsc{T}_A{=}25^{\circ}\textsc{C}$ and nominal \textsc{V}_{DD}

∆Idle "00" at M(0000), CL=50 pF.



2

Fig. 9 - Basic dc timing waveforms, one instruction cycle.

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SIGNAL DESCRIPTIONS

BUS 0 to BUS 7 (Data Bus):

8-bit bidirectional DATA BUS lines. These lines are used for transferring data between the memory, the microprocessor, and I/O devices.

N0 to N2 (I/O) Lines):

Activated by an I/O instruction to signal the I/O control logic of a data transfer between memory and I/O interface. These lines can be used to issue command codes or device selection codes to the I/O devices (independently or combined with the memory byte on the data bus when an I/O instruction is being executed). The N bits are low at all times except when an I/O instruction is being executed. During this time their state is the same as the corresponding bits in the N register.

The direction of data flow is defined in the I/O instruction by bit N3 (internally) and is indicated by the level of the MRD signal.

MRD=V_{CC}: Data from I/O to CPU and Memory MRD=V_{SS}: Data from Memory to I/O

EF1 to EF4 (4 Flags):

These inputs enable the I/O controllers to transfer status information to the processor. The levels can be tested by the conditional branch instructions. They can be used in conjunction with the INTERRUPT request line to establish interrupt priorities. These flags can also be used by I/O devices to "call the attention" of the processor, in which case the program must routinely test the status of these flag(s) are sampled at the beginning of every S1 cycle.

INTERRUPT, DMA-IN, DMA-OUT (3 I/O Requests)

These inputs are sampled by the CDP1802A during the interval between the leading edge of TPB and the leading edge of TPA.

Interrupt Action: X and P are stored in T after executing current instruction; designator X is set to 2; designator P is set to 1; interrupt enable is reset to 0 (inhibit); and instruction execution is resumed. The interrupt action requires one machine cycle (S3).

DMA Action: Finish executing current instruction; R(0) points to memory area for data transfer; data is loaded into or read out of memory; and increment R(0).

Note: In the event of concurrent DMA and Interrupt requests, DMA-IN has priority followed by DMA-OUT and then Interrupt.

SC0, SC1, (2 State Code Lines):

These outputs indicate that the CPU is: 1) fetching an instruction, or 2) executing an instruction, or 3) processing a DMA request, or 4) acknowledging an interrupt request. The levels of state code are tabulated below. All states are valid at TPA. $H=V_{CC}$, $L=V_{SS}$.

A 1 1 1 1 1 1 1 1 1 1	State Code Lines				
State Type	SC1	SC0			
S0 (Fetch)	L	L			
S1 (Execute)	L	н			
S2 (DMA)	н	L			
S3 (Interrupt)	н	н			

TPA, TPB (2 Timing Pulses):

Positive pulses that occur once in each machine cycle (TPB follows TPA). They are used by I/O controllers to interpret codes and to time interaction with the data bus. The trailing edge of TPA is used by the memory system to latch the higher-order byte of the 16-bit memory address. TPA is suppressed in IDLE when the CPU is in the load mode.

MA0 to MA7 (8 Memory Address Lines):

In each cycle, the higher-order byte of a 16-bit CPU memory address appears on the memory address lines MA0-7 first. Those bits required by the memory system can be strobed into external address latches by timing pulse TPA. The loworder byte of the 16-bit address appears on the address lines after the termination of TPA. Latching of all 8 higher-order address bits would permit a memory system of 64K bytes.

MWR (Write Pulse):

A negative pulse appearing in a memory-write cycle, after the address lines have stabilized.

MRD (Read Level):

A low level on MRD indicates a memory read cycle. It can be used to control three-state outputs from the addressed memory which may have a common data input and output bus. If a memory does not have a three-state high-impedance output, MRD is useful for driving memory/bus separator gates. It is also used to indicate the direction of data transfer during an I/O instruction. For additional information see Table I.

Q:

Single bit output from the CPU which can be set or reset under program control. During SEQ or REQ instruction execution, Q is set or reset between the trailing edge of TPA and the leading edge of TPB.

CLOCK:

Input for externally generated single-phase clock. A typical clock frequency is 6.4 MHz at V_{CC} = V_{DD} =10 volts. The clock is counted down internally to 8 clock pulses per machine cycle.

XTAL:

Connection to be used with clock input terminal, for an external crystal, if the on-chip oscillator is utilized. The crystal is connected between terminals 1 and 39 (CLOCK and XTAL) in parallel with a resistance (10 megohms typ.). Frequency trimming capacitors may be required at terminals 1 and 39. For additional information, see ICAN-6565.

WAIT, CLEAR (2 Control Lines):

Provide four control modes as listed in the following truth table:

CLEAR	WAIT	MODE
L	Ľ	LOAD
L	Н	RESET
н	L	PAUSE
н	н	RUN

VDD, VSS, VCC (Power Levels):

The internal voltage supply V_{DD} is isolated from the Input/Output voltage supply V_{CC} so that the processor may operate at maximum speed while interfacing with peripheral devices operating at lower voltage. V_{CC} must be less than or equal to V_{DD}. All outputs swing from V_{SS} to V_{CC}. The recommended input voltage swing is V_{SS} to V_{CC}.

ARCHITECTURE

The CPU block diagram is shown in Fig. 8. The principal feature of this system is a register array (R) consisting of sixteen 16-bit scratchpad registers. Individual registers in the array (R) are designated (selected) by a 4-bit binary code from one of the 4-bit registers labeled N, P, and X. The contents of any register can be directed to any one of the following three paths:

- 1. the external memory (multiplexed, higher-order byte first, on to 8 memory address lines);
- the D register (either of the two bytes can be gated to D);
- 3. the increment/decrement circuit where it is increased or decreased by one and stored back in the selected 16-bit register.

The three paths, depending on the nature of the instruction, may operate independently or in various combinations in the same machine cycle.

With two exceptions, CPU instructions consist of two 8clock-pulse machine cycles. The first cycle is the fetch cycle, and the second—and third if necessary—are execute cycles. During the fetch cycle the four bits in the P designator selectione of the 16 registers R(P) as the current program counter. The selected register R(P) contains the address of the memory location from which the instruction is to be fetched. When the instruction is read out from the memory, the higher-order 4 bits of the instruction byte are loaded into the I register and the lower-order 4 bits into the N register. The content of the program counter is automatically incremented by one so that R(P) is now "pointing" to the next byte in the memory.

The X designator selects one of the 16 registers R(X) to "point" to the memory for an operand (or data) in certain ALU or I/O operations.

The N designator can perform the following five functions depending on the type of instruction fetched:

- designate one of the 16 registers in R to be acted upon during register operations;
- indicate to the I/O devices a command code or deviceselection code for peripherals;
- Indicate the specific operation to be executed during the ALU instructions, types of tests to be performed during the Branch instructions, or the specific operation required in a class of miscellaneous instructions (70-73 and 78-7B);
- indicate the value to be loaded into P to designate a new register to be used as the program counter R(P);
- 5. indicate the value to be loaded into X to designate a new register to be used as data pointer R(X).

The registers in R can be assigned by a programmer in three different ways: as program counters, as data pointers, or as scratchpad locations (data registers) to hold two bytes of data.

Program Counters

Any register can be the main program counter; the address of the selected register is held in the P designator. Other registers in R can be used as subroutine program counters. By a single instruction the contents of the P register can be changed to effect a "call" to a subroutine. When interrupts are being serviced, register R(1) is used as the program counter for the user's interrupt servicing routine. After reset, and during a DMA operation, R(0) is used as the program counter. At all other times the register designated as program counter is at the discretion of the user.

Data Pointers

The registers in R may be used as data pointers to indicate a location in memory. The register designated by X (i.e., R(X)) points to memory for the following instructions (see Table I):

- 1. ALU operations F1-F5, F7, 74, 75, 77;
- 2. output instructions 61 through 67;
- 3. input instructions 69 through 6F;

4. certain miscellaneous instructions — 70-73, 78, 60, F0. The register designated by N (i.e., R(N)) points to memory for the "load D from memory" instructions 0N and 4N and the "Store D" instruction 5N. The register designated by P (i.e., the program counter) is used as the data pointer for ALU instructions F8-FD, FF, 7C, 7D, 7F. During these instruction executions, the operation is referred to as "data immediate".

Another important use of R as a data pointer supports the built-in Direct-Memory-Access (DMA) function. When a DMA-In or DMA-Out request is received, one machine cycle is "stolen". This operation occurs at the end of the execute machine cycle in the current instruction. Register R(0) is always used as the data pointer during the DMA operation. The data is read from (DMA-Out) or written into (DMA-In) the memory location pointed to by the R(0) register. At the end of the transfer, R(0) is incremented by one so that the processor is ready to act upon the next DMA byte transfer request. This feature in the 1800-series architecture saves a substantial amount of logic when fast exchanges of blocks of data are required, such as with magnetic discs or during CRT-display-refresh cycles.

Data Registers

When registers in R are used to store bytes of data, four instructions are provided which allow D to receive from or write into either the higher-order- or lower-order-byte portions of the register designated by N. By this mechanism (together with loading by data immediate) program pointer and data pointer designations are initialized. Also, this technique allows scratchpad registers in R to be used to hold general data. By employing increment or decrement instructions, such registers may be used as loop counters.

The Q Flip Flop

An internal flip flop, Q, can be set or reset by instruction and can be sensed by conditional branch instructions. The output of Q is also available as a microprocessor output.

Interrupt Servicing

Register R(1) is always used as the program counter whenever interrupt servicing is initiated. When an interrupt request occurs and the interrupt is allowed by the program (again, nothing takes place until the completion of the current instruction), the contents of the X and P registers are stored in the temporary register T, and X and P are set to new values; hex digit 2 in X and hex digit 1 in P. Interrupt Enable is automatically de-activated to inhibit further interruptions. The user's interrupt routine is now in control; the contents of T may be saved by means of a single instruction (78) in the memory location pointed to by R(X). At the conclusion of the interrupt, the user's routine may restore the pre-interrupted value of X and P with a single instruction (70 or 71). The Interrupt-Enable flip flop can be activated to permit further interrupts or can be disabled to prevent them.

CPU Register Summary

D	8 Bits	Data Register (Accumulator)
DF	1 Bit	Data Flag (ALU Carry)
В	8 Bits	Auxiliary Holding Register
R	16 Bits	1 of 16 Scratchpad Registers
P	4 Bits	Designates which register is
		Program Counter
Х	4 Bits	Designates which register is
L		Data Pointer

N	4 Bits	Holds Low-Order Instr. Digit
I	4 Bits	Holds High-Order Instr. Digit
Т	8 Bits	Holds old X, P after Interrupt
		(X is high nibble)
IE	1 Bit	Interrupt Enable
Q	1 Bit	Output Flip Flop

CDP1802 Control Modes

The WAIT and CLEAR lines provide four control modes as

PAUSE

RUN

CLEAR	WAIT	MODE
-	L	LOAD

listed in the following truth table:

H

н

The function of the modes are defined as follows:

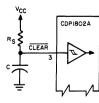
н

Load

Holds the CPU in the IDLE execution state and allows an I/O device to load the memory without the need for a "bootstrap" loader. It modifies the IDLE condition so that DMA-IN operation does not force execution of the next instruction.

Reset

Registers I, N, Q are reset, IE is set and 0's (V_{SS}) are placed on the data bus. TPA and TPB are suppressed while reset is held and the CPU is placed in S1. The first machine cycle after termination of reset is an initialization cycle which requires 9 clock pulses. During this cycle the CPU remains in S1 and registers X, P, and R(0) are reset. Interrupt and DMA servicing are suppressed during the initialization cycle. The next cycle is an S0, S1, or an S2 but never an S3. With the use of a 71 instruction followed by 00 at memory locations 0000 and 0001, this feature may be used to reset IE, so as to preclude interrupts until ready for them. Powerup reset can be realized by connecting an RC network directly to the CLEAR pin, since it has a Schmitt-triggered input, see Fig. 10.



The RC time constant should be greater than the oscillator start-up time (typically 20 ms).

92CS-33873

Stops the internal CPU timing generator on the first negative high-to-low transition of the input clock. The oscillator continues to operate, but subsequent clock transitions are ignored.

Bun

Pause

May be initiated from the Pause or Reset mode functions. If initiated from Pause, the CPU resumes operation on the first negative high-to-low transition of the input clock. When initiated from the Reset operation, the first machine cycle following Reset is always the initialization cycle. The initialization cycle is then followed by a DMA (S2) cycle or fetch (S0) from location 0000 in memory.

RUN-MODE STATE TRANSITIONS

The CDP1802A CPU state transitions when in the RUN and RESET modes are shown in Fig. 11. Each machine cycle requires the same period of time, 8 clock pulses, except the initialization cycle, which requires 9 clock pulses. The execution of an instruction requires either two or three machine cycles, S0 followed by a single S1 cycle or two S1 cycles. S2 is the response to a DMA request and S3 is the interrupt response. Table II shows the conditions on Data Bus and Memory-Address lines during all machine states.

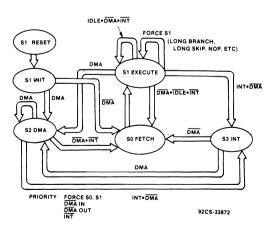


Fig. 11 - State transition diagram.

INSTRUCTION SET

The CPU instruction summary is given in Table I. Hexadecimal notation is used to refer to the 4-bit binary codes.

In all registers bits are numbered from the least significant bit (LSB) to the most significant bit (MSB) starting with 0.

R(W): Register designated by W, where W=N or X, or P R(W).0: Lower-order byte of R(W) R(W).1: Higher-order byte of R(W)

Operation Notation

 $M(R(N)) \rightarrow D; R(N) + 1 \rightarrow R(N)$

This notation means: The memory byte pointed to by R(N) is loaded into D, and R(N) is incremented by 1.

		OP	
INSTRUCTION	MNEMONIC	CODE	OPERATION
MEMORY REFERENCE			
LOAD VIA N	LDN	ON	M(R(N))→D; FOR N NOT 0
LOAD ADVANCE	LDA	4N	M(R(N))→D; (RN)+1 →R(N)
LOAD VIA X	LDX	F0	M(R(X))→D
LOAD VIA X AND ADVANCE	LDXA	72	M(R(X))→D; R(X)+1→R(X)
LOAD IMMEDIATE	LDI	F8	M(R(P))→D; R(P)+1→R(P)
STORE VIA N	STR	5N	D→M(R(N))
STORE VIA X AND	STXD	73	D→M(R(X)); R(X)−1→R(X)
DECREMENT			
REGISTER OPERATIONS			
INCREMENT REG N	INC	1N	R(N)+1→R(N)
DECREMENT REG N	DEC	2N	R(N)−1→R(N)
INCREMENT REG X	IRX	60	R(X)+1→R(X)
GET LOW REG N	GLO	8N	R(N).0→D
PUT LOW REG N	PLO	AN	D→R(N).0
GET HIGH REG N	GHI	9N	R(N).1→D
PUT HIGH REG N	PHI	BN	D→R(N).1
LOGIC OPERATIONS \$			
OR	OR	F1	M(R(X)) OR D→D
OR IMMEDIATE	ORI	F9	M(R(P)) OR D→D;
			R(P)+1→R(P)
EXCLUSIVE OR	XOR	F3	M(R(X)) XOR D→D
EXCLUSIVE OR IMMEDIATE	XRI	FB	M(R(P)) XOR D→D;
			R(P)+1→R(P)
AND	AND	F2	M(R(X)) AND D→D
AND IMMEDIATE	ANI	FA	M(R(P)) AND D→D;
			R(P)+1→R(P)
SHIFT RIGHT	SHR	F6	SHIFT D RIGHT, LSB(D)→DF,
			O→MSB(D)
SHIFT RIGHT WITH CARRY	SHRC	76§	SHIFT D RIGHT, LSB(D)→DF,
	}		DF→MSB(D)
RING SHIFT RIGHT	RSHR)		
SHIFT LEFT	SHL	FE	SHIFT D LEFT, MSB(D)→DF,
			0→LSB(D)
SHIFT LEFT WITH CARRY	SHLC	7E§	SHIFT D LEFT, MSB(D)→DF,
	}		DF→LSB(D)
RING SHIFT LEFT	RSHL)		

2

			OP	
INSTRUCTION	M	INEMONIC	CODE	OPERATION
ARITHMETIC OPERATIONS \$	-			
ADD	ADD		F4	M(R(X))+D→DF, D
ADD IMMEDIATE	ADI		FC	M(R(P))+D→DF,D; R(P)+1→R(P)
ADD WITH CARRY	ADC		74	M(R(X))+D+DF→DF, D
ADD WITH CARRY, IMMEDIATE	ADCI		7C	M(R(P))+D+DF→DF, D
				R(P)+1→R(P)
SUBTRACT D	SD		F5	M(R(X))−D→DF, D
SUBTRACT D IMMEDIATE	SDI		FD	$M(R(P)) - D \rightarrow DF, D;$
				R(P)+1→R(P)
SUBTRACT D WITH BORROW	SDB		75	M(R(X))−D−(NOT DF)→DF, D
SUBTRACT D WITH	SDBI		7D	M(R(P))−D−(NOT DF)→DF, D;
BORROW, IMMEDIATE				R(P)+1→R(P)
SUBTRACT MEMORY	SM		F7	D−M(R(X))→DF, D
SUBTRACT MEMORY IMMEDIATE	SMI		FF	DM(R(P))→DF, D;
				R(P)+1→R(P)
SUBTRACT MEMORY WITH BORROW	SMB		77	D−M(R(X))−(NOT DF)→DF, D
SUBTRACT MEMORY WITH	SMBI		7F	D−M(R(P))−(NOT DF)→DF, D
BORROW, IMMEDIATE				$R(P)+1\rightarrow R(P)$
BRANCH INSTRUCTIONS-SHORT BR	ANCH		L	
SHORT BRANCH	BR	**************************************	30	M(R(P))→R(P).0
NO SHORT BRANCH (SEE SKP)	NBR		38§	$R(P)+1 \rightarrow R(P)$
SHORT BRANCH IF D=0	BZ		32	IF D=0, M(R(P))→R(P).0
				ELSE R(P)+1 \rightarrow R(P)
SHORT BRANCH IF D NOT 0	BNZ		3A	IF D NOT 0, $M(R(P)) \rightarrow R(P).0$
				ELSE R(P)+1 \rightarrow R(P)
SHORT BRANCH IF DF=1	BDF)	33§	IF DF=1, M(R(P)) \rightarrow R(P).0
SHORT BRANCH IF POS OR ZERO	BPZ	(ELSE R(P)+1 \rightarrow R(P)
SHORT BRANCH IF EQUAL OR	BGE			
GREATER	Duc	,		
SHORT BRANCH IF DF=0	BNF)	ЗB§	IF DF=0, M(R(P))→R(P).0
SHORT BRANCH IF MINUS	ВМ	(020	ELSE R(P)+1 \rightarrow R(P)
SHORT BRANCH IF LESS	BL	\mathbf{I}		
SHORT BRANCH IF Q=1	BQ)	31	IF Q=1, M(R(P))→R(P).0
				ELSE R(P)+1 \rightarrow R(P)
SHORT BRANCH IF Q=0	BNQ		39	IF Q=0, M(R(P)) \rightarrow R(P).0
				ELSE R(P)+1 \rightarrow R(P)
SHORT BRANCH IF EF1=1	B1		34	IF EF1=1, $M(R(P)) \rightarrow R(P).0$
(EF1=VSS)				ELSE $R(P)+1 \rightarrow R(P)$
SHORT BRANCH IF EF1=0	BN1		3C	IF EF1=0, M(R(P)) \rightarrow R(P).0
(EF1=VCC)				ELSE $R(P)+1 \rightarrow R(P)$
SHORT BRANCH IF EF2=1	В2		35	IF EF2=1, M(R(P)) \rightarrow R(P).0
(EF2=VSS)				ELSE R(P)+1 \rightarrow R(P)
SHORT BRANCH IF EF2=0	BN2		3D	
_			30	IF EF2=0, M(R(P)) \rightarrow R(P).0
	вз		26	ELSE $R(P)+1 \rightarrow R(P)$
SHORT BRANCH IF EF3=1	63		36	IF EF3=1, M(R(P)) \rightarrow R(P).0
(EF3=VSS)			25	ELSE $R(P)+1 \rightarrow R(P)$
SHORT BRANCH IF EF3=0	BN3		3E	IF EF3=0, M(R(P))→R(P).0
(EF3=V _{CC})				ELSE R(P)+1→R(P)

TABLE I - INSTRUCTION SUMMARY (Cont'd)

TABLE I -- INSTRUCTION SUMMARY (Cont'd)

INSTRUCTION	MNEMONIC	OP CODE	OPERATION	
BRANCH INSTRUCTIONS-SHORT		1 0000		
SHORT BRANCH IF EF4=1 (EF4=VSS)	B4	37	IF EF4=1, M(R(P))→R(P).0 ELSE R(P)+1→R(P)	
SHORT BRANCH IF EF4=0	BN4	ЗF	IF EF4=0, M(R(P))→R(P).0 ELSE R(P)+1→R(P)	
BRANCH INSTRUCTIONS-LONG BI		1		-
LONG BRANCH	LBR	CO	M(R(P))→R(P).1	
			M(R(P)+1)→R(P).0	
NO LONG BRANCH (SEE LSKP)	NLBR	C8§	R(P)+2→R(P)	
LONG BRANCH IF D=0	LBZ	C2	IF D=0, M(R(P))→R(P).1 M(R(P)+1)→R(P).0	
			ELSE R(P)+2→R(P)	
LONG BRANCH IF D NOT 0	LBNZ	CA	IF D NOT 0, M(R(P))→R(P).1 M(R(P)+1)→R(P).0	
LONG BRANCH IF DF=1	LBDF	СЗ	ELSE R(P)+2→R(P) IF DF=1, M(R(P))→R(P).1 M(R(P)+1)→R(P).0	
			ELSE R(P)+2→R(P)	
LONG BRANCH IF DF=0	LBNF	СВ	IF DF=0, M(R(P))→R(P).1	
			M(R(P)+1)→R(P).0	
			ELSE R(P)+2→R(P)	
LONG BRANCH IF Q=1	LBQ	C1	IF Q=1, M(R(P))→R(P).1	
			M(R(P)+1)→R(R).0	
LONG BRANCH IF Q=0			ELSE R(P)+2→R(P)	
LONG BRANCH IF Q=0	LBNQ	C9	IF Q=0, M(R(P))→R(P).1 M(R(P)+1)→R(P).0	
			ELSE R(P)+2 \rightarrow R(P)	
SKIP INSTRUCTIONS				
SHORT SKIP (SEE NBR)	SKP	38§	R(P)+1→R(P)	
LONG SKIP (SEE NLBR)	LSKP	C8§	R(P)+2→R(P)	
LONG SKIP IF D=0	LSZ	CE	IF D=0, R(P)+2→R(P)	
			ELSE CONTINUE	
LONG SKIP IF D NOT 0	LSNZ	C6	IF D NOT 0, R(P)+2→R(P)	
			ELSE CONTINUE	
LONG SKIP IF DF=1	LSDF	CF	IF DF=1, R(P)+2→R(P)	
			ELSE CONTINUE	
LONG SKIP IF DF=0	LSNF	C7	IF DF=0, R(P)+2→R(P)	
			ELSE CONTINUE	
LONG SKIP IF Q=1	LSQ	CD	$IF Q=1, R(P)+2 \rightarrow R(P)$	
	LSNQ	C5		
LONG SKIP IF Q=0	LONG		IF Q=0, R(P)+2→R(P) ELSE CONTINUE	
LONG SKIP IF IE=1	LSIE	сс	ELSE CONTINUE IF IE=1, R(P)+2→R(P) ELSE CONTINUE	

		1	
		OP	
INSTRUCTION	MNEMONIC	CODE	OPERATION
CONTROL INSTRUCTIONS			
IDLE	IDL	00#	WAIT FOR DMA OR INTERRUPT;
			M(R(0))→BUS
NO OPERATION	NOP	C4	CONTINUE
SET P	SEP	DN	N→P
SET X	SEX	EN	N→X
SET Q	SEQ	7B	1 → Q
RESET Q	REQ	7A	0Q
SAVE	SAV	78	T→M(R(X))
PUSH X,P TO STACK	MARK	79	(X,P)→T; (X,P)→M(R(2))
			THEN P→X; R(2)−1→R(2)
RETURN	RET	70	M(R(X))→(X,P); R(X)+1→R(X)
			1→IE
DISABLE	DIS	71	M(R(X))→(X,P); R(X)+1→R(X)
			0→IE
INPUT-OUTPUT BYTE TRANSFER			
OUTPUT 1	OUT 1	61	$M(R(X)) \rightarrow BUS; R(X) + 1 \rightarrow R(X); N LINES=1$
OUTPUT 2	OUT 2	62	$M(R(X)) \rightarrow BUS; R(X) + 1 \rightarrow R(X); N LINES = 2$
OUTPUT 3	OUT 3	63	$M(R(X)) \rightarrow BUS; R(X) + 1 \rightarrow R(X); N LINES = 3$
OUTPUT,4	OUT 4	64	M(R(X))→BUS;R(X)+1→R(X); N LINES=4
OUTPUT 5	OUT 5	65	$M(R(X)) \rightarrow BUS; R(X)+1 \rightarrow R(X); N LINES=5$
OUTPUT 6	OUT 6	66	$M(R(X)) \rightarrow BUS; R(X)+1 \rightarrow R(X); N LINES=6$
OUTPUT 7	OUT 7	67	$M(R(X)) \rightarrow BUS; R(X) + 1 \rightarrow R(X); N LINES = 7$
INPUT 1	INP 1	69	BUS→M(R(X)); BUS→D; N LINES=1
INPUT 2	INP 2	6A	BUS→M(R(X)); BUS→D; N LINES=2
INPUT 3	INP 3	6B	BUS→M(R(X)); BUS→D; N LINES=3
INPUT 4	INP 4	6C	BUS→M(R(X)); BUS→D; N LINES=4
INPUT 5	INP 5	6D	BUS→M(R(X)); BUS→D; N LINES=5
INPUT 6	INP 6	6E	BUS→M(R(X)); BUS→D; N LINES=6
INPUT 7	INP 7	6F	BUS→M(R(X)); BUS→D; N LINES=7

TABLE I - INSTRUCTION SUMMARY (Cont'd)

Notes

THE ARITHMETIC OPERATIONS AND THE SHIFT INSTRUCTIONS ARE THE ONLY INSTRUCTIONS THAT CAN ALTER THE DF AFTER AN ADD INSTRUCTION:

DF=1 DENOTES A CARRY HAS OCCURRED

DF=0 DENOTES A CARRY HAS NOT OCCURRED

AFTER A SUBTRACT INSTRUCTION

DF=1 DENOTES NO BORROW D IS A TRUE POSITIVE NUMBER

DF=0 DENOTES A BORROW D IS TWO'S COMPLEMENT

THE SYNTAX "-(NOT DF)" DENOTES THE SUBTRACTION OF THE BORROW

\$THIS INSTRUCTION IS ASSOCIATED WITH MORE THAN ONE MNEMONIC EACH MNEMONIC IS INDIVIDUALLY LISTED

#AN IDLE INSTRUCTION INITIATES A REPEATING S1 CYCLE THE PROCESSOR WILL CONTINUE TO IDLE UNTIL AN I/O REQUEST (INTERRUPT, DMA-IN, OR DMA-OUT) IS ACTIVATED WHEN THE REQUEST IS ACKNOWLEDGED, THE IDLE CYCLE IS TERMINATED AND THE I/O REQUEST IS SERVICED, AND THEN NORMAL OPERATION IS RESUMED

Notes for TABLE I

1. Long-Branch, Long-Skip and No Op instructions are the only instructions that require three cycles to complete (1 fetch +2 execute).

Long-Branch instructions are three bytes long. The first byte specifies the condition to be tested; and the second and third byte, the branching address.

The long-branch instructions can:

- a) Branch unconditionally
- b) Test for D=0 or D=0
- c) Test for DF=0 or DF=1
- d) Test for Q=0 or Q=1
- e) effect an unconditional no branch

If the tested condition is met, then branching takes place; the branching address bytes are loaded in the high- and low-order bytes of the current program counter, respectively. This operation effects a branch to any memory location.

If the tested condition is not met, the branching address bytes are skipped over, and the next instruction in sequence is fetched and executed. This operation is taken for the case of unconditional no branch (NLBR).

The short-branch instructions are two bytes long. The first byte specifies the condition to be tested, and the second specifies the branching address.

The short-branch instruction can:

- a) Branch unconditionally
- b) Test for D=0 or D=0
- c) Test for DF=0 or DF=1
- d) Test for Q=0 or Q=1
- e) Test the status (1 or 0) of the four EF flags
- f) Effect an unconditional no branch

If the tested condition is met, then branching takes place; the branching address byte is loaded into the low-order byte position of the current program counter. This effects a branch within the current 256byte page of the memory, i.e., the page which holds the branching address. If the tested condition is not met, the branching address byte is skipped over, and the next instruction in sequence is fetched and executed. This same action is taken in the case of unconditional no branch (NBR).

The skip instructions are one byte long. There is one Unconditional Short-Skip (SKP) and eight Long-Skip instructions.

The Unconditional Short-Skip instruction takes 2 cycles to complete (1 fetch + 1 execute). Its action is to skip over the byte following it. Then the next instruction in sequence is fetched and executed. This SKP instruction is identical to the unconditional no-branch instruction (NBR) except that the skipped-over byte is not considered part of the program

The Long-Skip instructions take three cycles to complete (1 fetch +2 execute).

They can:

- a) Skip unconditionally
- b) Test for D=0 or D=0
- c) Test for DF=0 or DF=1
- d) Test for Q=0 or Q=1
- e) Test for IE=1

If the tested condition is met, then Long Skip takes place; the current program counter is incremented twice Thus two bytes are skipped over and the next instruction in sequence is fetched and executed. If the tested condition is not met, then no action is taken.

Execution is continued by fetching the next instruction in sequence.

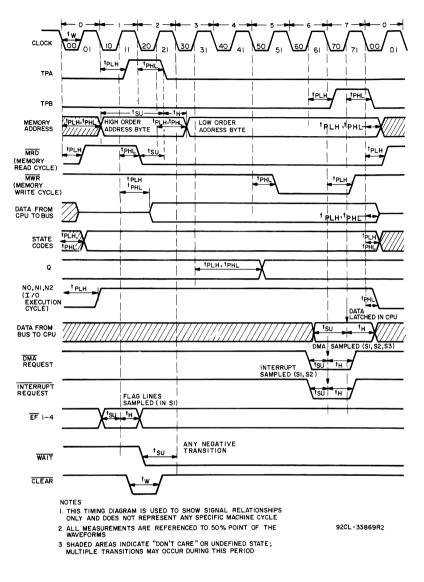


Fig. 12 - Timing waveforms

DYNAMIC ELECTRICAL CHARACTERISTICS at T	A=-40 to +85°C, CL=	50 pF, VDD±5%, except as noted.
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CHARACTERISTIC		Vcc	VDD	LIN	IITS	UNITS
CHARACTERISTIC		(V)	(V)	Тур.●	Max.	UNITS
opagation Delay Times:	·					
		5	5	200	300	
Clock to TPA, TPB	tPLH, tPHL	5	10	150	250	
	4 610 4116	10	10	100	150	
		5	5	600	850	
Clock-to-Memory High-Address Byte	^t PLH ^{, t} PHL	5	10	400	600	
	PLA, PAL	10	10	300	400	
		5	5	250	350	
Clock-to-Memory Low-Address Byte Valid	*****			250 150	250	
Clock-to-Memory Low-Address Byte Valid	^t PLH, ^t PHL	5	10			
		10	10	100	150	
		5	5	200	300	
Clock to MRD	^t PHL	5	10	150	250	
		10	10	100	150	
		5	5	200	350	
Clock to MRD	^t PLH	5	10	150	290	
		10	10	100	175	
		5	5	200	300	
Clock to MWR	tPLH, tPHL	5	10	150	250	
		10	10	100	150	
		5	5	300	450	
Clock to (CPU DATA to BUS) Valid	to u tou	5	10	250	350	
	^t PLH ^{, t} PHL	10	10	100	200	
	······	5	5			ns
				300	450	
Clock to State Code	^t PLH ^{, t} PHL	5	10	250	350	
		10	10	150	250	
		5	5	250	400	
Clock to Q	^t PLH, ^t PHL	5	10	150	250	
		10	10	100	150	
		5	5	300	550	
Clock to N (0-2)	^t PLH, ^t PHL	5	10	200	350	
		10	10	150	250	
nimum Setup and Hold Times:						
		5	5	-20	25	
Data Bus Input Setup	ts∪	5	10	0	50	
		10	10	-10	40	
	······································	5	5	150	200	
Data Bus Input Hold	tH∎	5	10	100	125	
	-11	10	10	75	100	
		5	5	0	30	
MA Satur	terr	5	10	0	20	
DMA Setup	tsu		10			
		10		0	10	
	. •	5	5	150	250	
DMA Hold	tH■	5	10	100	200	
		10	10	75	125	
		5	5	-75	0	
Interrupt Setup	tsu	5	10	-50	0	
		10	10	-25	0	

 $^{\bullet}$ Typical values are for TA=25°C and nominal VDD

Maximum limits of minimum characteristics are the values above which all devices function

DYNAMIC ELECTRICAL CHARACTERISTICS (Cont'd)

		Vcc	VDD	LIM	ITS	
CHARACTERISTIC		(V)	(V)	Тур.•	Max.	UNITS
Minimum Setup and Hold Times		_	_		450	
		5	5	100	150	
Interrupt Hold	tH e	5	10	75	100	
		10	10	50	75	
		5	5	10	50	
WAIT Setup	tsu	5	10	-10	15	
		10	10	0	25	
		5	5	-30	20	
EF1-4 Setup	ts∪	5	10	-20	30	
		10	10	-10	40	
		5	5	150	200	ns
EF1-4 Hold	tH∎	5	10	100	150	
		10	10	75	100	
Minimum Pulse Width Times:						
		5	5	150	300	
CLEAR Pulse Width	tw∟	5	10	100	200	
		10	10	75	150	
		5	5	125	150	1
CLOCK Pulse Width	twL	5	10	100	125	
		10	10	60	75	

•Typical values are for $T_A=25^{\circ}C$ and nominal V_{DD} .

Maximum limits of minimum characteristics are the values above which all devices function.

CHARACTERISTIC		Vcc	VDD	LIM	ITS	UNITS
CHARACTERISTIC		(V)	(V)	Min.	Тур.•	UNITS
High-Order Memory-Address Byte		5	5	2T-550	2T-400	
Set Up to TPA – Time	ts∪	5	10	2T-350	2T-250	
		10	10	2T-250	2T-200	
High-Order Memory-Address Byte		5	5	T/2-25	T/2-15	
Hold after TPA Time	tн	5	10	T/2-35	T/2-25	
		10	10	T/2-10	T/2+0	
Low-Order Memory-Address Byte		5	5	T-30	T+0	1
Hold after WR Time	tн	5	10	T-20	T+0	
		10	10	T-10	T+0	
CPU Data to Bus Hold		5	5	T-200	T-150	ns
after WR Time	t _H	5	10	T-150	T-100	
		10	10	T-100	T-50	
Required Memory Access Time		5	5	5T-375	5T-250	1
Address to Data	tacc	5	10	5T-250	5T-150	
		10	10	5T-190	5T-100	
		5	5	T/2-25	T/2-18	1
MRD to TPA (🔌)	tsu	5	10	T/2-20	T/2-15	
		10	10	T/2-15	T/2-10	1

TIMING SPECIFICATIONS as a function of T(T=1/fCLOCK) at TA=-40 to +85°C

•Typical values are for $T_A{=}25^\circ\,C$ and nominal V_{DD}

TABLE II. CONDITIONS ON DATA BUS AND MEMORY ADDRESS LINES DURING

				ALL M/	ACHINE STAT	ES				
					DATA	MEMORY			N	
STATE	<u> </u>	N	MNEMONIC	OPERATION	BUS	ADDRESS	MRD	MWR	LINES	NOTESG
S1		RES	ET	0→I,N,Q,X,P; 1→IE	00	хххх	1	1	0	A
S1	NC	INITIA OT PROG ACCES	RAMMER	0000 ⊸ R	00	xxxx	1	1	0	В
S0		FET		MRP→I, N; RP+1→RP	MRP	RP	0	1	0	С
	0	0	IDL	IDLE	MR0	R0	0	1	0	D,3
	0	1-F	LDN	MRN→D	MRN	RN	0	1	0	3
	1	0-F	INC	RN+1→RN	FLOAT	RN	1	1	0	1
	2	U-F	DEC	RN–1→RN	FLOAT	RN	1	1	0	1
	3	0-F	SHORT BRANCH	TAKEN; MRP→RP.0 NOT TAKEN; RP+1→RP	MRP	RP	0	1	0	3
	4	0-F	LDA	MRN→D; RN+1→RN	MRN	RN	0	1	0	3
	5	0-F	STR	D→MRN	D	RN	1	0	0	2
S1	6	0	IRX	RX+1-RX	MRX	RX	0	1	0	2
		1 2 3	OUT 1 OUT 2 OUT 3						1 2 3	
		4 5 6 7	OUT 4 OUT 5 OUT 6 OUT 7	MRX→BUS; RX+1→RX	MRX	RX	0	1	4 5 6 7	6
	6	9 A B C D E F	INP 1 INP 2 INP 3 INP 4 INP 5 INP 6 INP 7	BUSMRX,D	DATA FROM I/O DEVICE	RX	1	0	1 2 3 4 5 6 7	5
		0	RET	MRX→(X,P), RX+1→RX; 1→IE	MRX	RX	0	1	0	3
		1	DIS	MRX→(X,P), RX+1→RX, 0→IE	MRX	RX	0	1	0	3
	7	2	LDXA	MRX→D; RX+1→RX	MRX	RX	0	1	0	3
		3	STXD	D→MRX; RX−1→RX	D	RX	1	0	0	2
		4	ADC	MRX+D+ DF→DF,D	MRX	RX	0	1	0	3

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TABLE II. CONDITIONS ON DATA BUS AND MEMORY ADDRESS LINES DURING ALL MACHINE STATES (CONT'D)

					E STATES (C				Ν	
STATE					DATA	MEMORY			N	NOTESG
STATE	<u> </u>	N	MNEMONIC	OPERATION	BUS	ADDRESS	MRD	MWR	LINES	
		5	SDB	MRX-D-	MRX	RX	0	1	0	3
				DFN→DF,D						
		6	SHRC	LSB(D)→DF,	FLOAT	RX	1	1	0	1
				DF→MSB(D)						
		7	SMB	D-MRX-	MRX	RX	0	1	0	3
				DFN→DF,D				ļ		
S1	7	8	SAV	T→MRX	Υ	RX	11	0	0	2
		9	MARK	(X,P)→T, MR2,	т	R2	1	0	0	2
				P→X, R2-1→R2						
	.	A	REQ	0→Q	FLOAT	RP	1	1	0	1
		В	SEQ	1→Q	FLOAT	RP	1	1	0	1
		С	ADCI	MRP+D+	MRP	RP	0	1	0	3
				DF→DF,D, RP+1						
		D	SDBI	MRP-D-	MRP	RP	0] 1	0	3
				DFN→DF,D,						
				RP+1						
		E	SHLC	MSB(D)→DF,	FLOAT	RP	1	1	0	1
				DF→LSB(D)						
		F	SMBI	D-MRP-	MRP	RP	0	1	0	3
				DFN-DF,D,						
				RP+1						
	8	0-F	GLO	RN 0→D	RN.0	RN	1	1	0	1
	9	0-F	GHI	RN 1→D	RN 1	RN	1	1	0	1
	Α	0-F	PLO	D→RN 0	D	RN	1	1	0	1
	В	0-F	PHI	D→RN 1	D	RN	1	1	0	1
S1#1				TAKEN MRP→B,	MRP	RP	0	1	0	4
				RP+1→RP						
#2			LONG	TAKEN B→RP.1,	M(RP+1)	RP+1	0	1	0	4
		0-3,	BRANCH	MRP-RP 0						
S1#1	1	8-B		NOT TAKEN	MRP	RP	0	1	0	4
				RP+1→RP						
#2	l c	[NOT TAKEN	M(RP+1)	RP+1	0	1	0	4
				RP+1→RP						
S1#1	I	5		TAKEN RP+1→RP	MRP	RP	0	1	0	4
	1	6						1		
#2		7	LONG	TAKEN RP+1→RP	M(RP+1)	RP+1	0	1	0	4
		c	SKIP						, in the second se	-
S1#1		D		NOT TAKEN:	MRP	RP	0	1	0	4
		E		NO OPERATION				1		
#2	1	F		NOT TAKEN:	MRP	BP	0		0	4
				NO OPERATION		1	ľ	'	ľ	
S1#1			1	NO OPERATION	MRP	RP	0	1	0	4
51#1		4	NOP				<u>ــــــــــــــــــــــــــــــــــــ</u>	<u> </u>		<u> </u>
#2		"	NOF	NO OPERATION	MRP	BP	0	1	o	4
							<u> </u>		Ľ	1 1

			1	Γ	DATA	MEMORY			N	
STATE	1	N	MNEMONIC	OPERATION	BUS	ADDRESS	MRD	MWR	LINES	NOTES
	D	0-F	SEP	N→P	NN	RN	1	1	0	1
	E	0-F	SEX	N→X	NN	RN	1	1	0	1
		0	LDX	MRX-D	MRX	RX	0	1	0	3
		1	OR	MRX OR D→D						
		2	AND	MRX AND D-D						
		3	XOR	MRX XOR D→D	MRX	RX	0	1	0	3
		4	ADD	MRX+D→DF,D						
		5	SD	MRXD-→DF,D						
		7	SM	D-MRX→ĎF,D						
S1		6	SHR	LSB(D)→DF;	FLOAT	RX	1	1	0	1
				0→MSB(D)						
	F	8	LDI	MRP→D,						
				RP+1→RP						
		9	ORI	MRP OR D→D;						
				RP+1→RP	1					
		Α	ANI	MRP AND D→D;						
				RP+1→RP						
		в	XRI	MRP XOR D→D,	MRP	RP	0	1	0	3
				RP+1→RP						
		С	ADI	MRP+D→DF,D,						
				RP+1→RP						
		D	SDI	MRPD-→DF,D;					1	
				RP+1→RP						
		F	SMI	D−MRP→DF,D,						
				RP+1→RP						
		Е	SHL	MSB(D)→DF;	FLOAT	RP	1	1	0	1
				0→LSB(D)						
		DMA	IN	BUS→MR0;	DATA FROM	R0	1	0	0	F, 7
S2				R0+1→R0	I/O DEVICE					
		DMA C	DUT	MR0→BUS,	MR0	R0	0	1	0	F, 8
				R0+1→R0						
S3		INTERF	RUPT	X,P→T, 0→IE	FLOAT	RN	1	1	0	9
				1→P, 2→X						
S1		LOA	D	IDLE	M(R0-1)	R0-1	0	1	0	E,3
				(CLEAR, WAIT=0)						

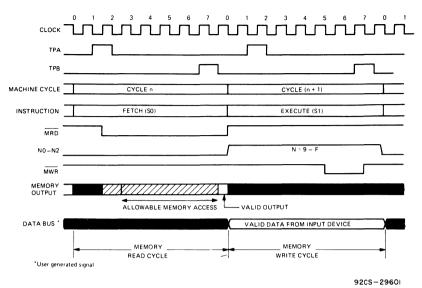
TABLE II. CONDITIONS ON DATA BUS AND MEMORY ADDRESS LINES DURING ALL MACHINE STATES (CONT'D)

NOTES:

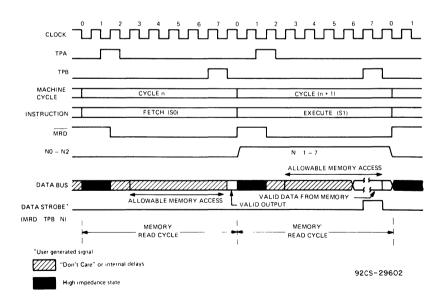
- A. IE=1, TPA, TPB suppressed, state=S1.
- B BUS=0 for entire cycle.
- C. Next state always S1.
- D. Wait for DMA or INTERRUPT.
- E. Suppress TPA, wait for DMA
- F. IN REQUEST has priority over OUT REQUEST.
- G. Number refers to machine cycle. See Fig 13 timing waveforms for machine cycles 1 through 9.

CLOCK	൜൜൜	സ്സ്സ്	ŴŴŴŴ	uuuu	ഹ്ന്ന്	സ്സ്സ്
TPA					-1	
трв		l				۱
MACHINE CYCLE	CYCLE n	CYCLE to + 1	CYCL	E (n + 2)	CYCLE (n + 3)	CYCLE (n + 4)
ма	HIGH ADD LOW ADDRESS	HIGH ADD LOW ADD	DRESS HIGH ADD L	OW ADDRESS HIGH	ADD LOW ADDRESS	HIGH ADD LOW
General t	tımıng wavəforms.					
INSTRUCTION	FETCH (SO)			H (SO)	EXECUTE (S1)	FETCH (SO)
MRD				ſ		
MWR (HIGH)						
MEMORY OUTPUT	ALLOWABLE MEMORY ACCESS					
No. 1 No.	n-memory-cycle timing w					
INSTRUCTION	FETCH (S0)	EXECUTE (4	1) FET	CH (SO)	EXECUTE (S1)	FETCH (SO)
MRD	MEMORY READ CYCLE	MEMORY & RITE (YELE-	READ CYCLE	MEMORY WRITE CYCLE	MEMORY READ CYCLE
MWR		L				
MEMORY OUTPUT	A contraction of the second se					
OUTPUT CPU OUTPUT TO	ALLOWABLE MEMORY ACCESS	VALID OUTPUT	A1A	OF F	ALID OUTPUT VALID DATA	OFF
OUTPUT CPU OUTPUT TO MEMORY No. 2 Me	ALLOWABLE MEMORY ACCESS	vauetorms		OFF	VALIDDATA	
OUTPUT CPU OUTPUT TO MEMORY	ALLOWABLE MEMORY ACCESS	vauo b vaveforms Extrute o	51) FET	OFF CH (SO)	EXECUTE (\$1)	FETCH (SO)
OUTPUT CPU OUTPUT TO MEMORY No. 2 Me	ALLOWABLE MEMORY ACCESS	vauo b vaveforms Extrute o	51) FET	OFF	VALIDDATA	
OUTPUT CPU OUTPUT TO MEMORY NO. 2 Me	ALLOWABLE ME MORY ACCESS	vauo b vaveforms Extrute o	51) FET	OFF CH (SO)	EXECUTE (\$1)	FETCH (SO) MEMORY READ
OUTPUT CPU OUTPUT TO MEMORY NO. 2 Me	ALLOWABLE MEMORY ACCESS		51) FET	OFF	EXECUTE (\$1)	FETCH (SO) MEMORY READ
OUTPUT CPU OUTPUT TO MEMORY NO. 2 Me INSTRUCTION MRD MWR (HIGH) MEMORY OUTPUT	ALLOWABLE MEMORY ACCESS		511 FET	OFF	EXECUTE (SI) -MEMORY READ CYCLE-	FETCH (SO) Hendry READ CYCLE
OUTPUT CPU OUTPUT TO MEMORY NO. 2 Me INSTRUCTION MRD MWR (HIGH) MEMORY OUTPUT NO. 3 Me	ALLOWABLE MEMORY ACCESS	VALID D vaveforms IXECUTE MEMORY READ () MEMORY READ () VALID OUTPUT vaveforms. Execute	S11 FET (LI	OFF	EXECUTE (SI) -MEMORY READ CYCLE-	FETCH (SO) MEMORY READ CYCLE VALID OUTPUT EXECUTE (S1) MEMORY READ
OUTPUT CPU OUTPUT TO MEMORY NO. 2 Me INSTRUCTION MRD MWR (HIGH) MEMORY OUTPUT NO. 3 Me	ALLOWABLE MEMORY ACCESS	VALID D vaveforms IXECUTE MEMORY READ () MEMORY READ () VALID OUTPUT vaveforms. Execute	S11 FET (LI	OFF	EXECUTE (SI) MEMORY READ CYCLE ALID OUTPUT FETCH (SD)	FETCH (SO) MEMORY READ CYCLE
OUTPUT CPU OUTPUT TO MEMORY NO. 2 Me INSTRUCTION MRD MWR (HIGH) MEMORY OUTPUT NO. 3 Me	ALLOWABLE MEMORY ACCESS OFF mory write-cycle timing v FFTCH (S0) MEMORY READ CYCLE ALLOWABLE MEMORY ACCESS ALLOWABLE MEMORY ACCESS MEMORY READ CYCLE MEMORY READ CYCLE	VALID D VALID	S11 FET (L1	OFF	EXECUTE (SI) MEMORY READ CYCLE ALID OUTPUT FETCH (SD) MEMORY READ CYCLE	FETCH (S0) MEMORY READ CYCLE VALID OUTPUT EXECUTE (S1) MEMORY READ
OUTPUT CPU OUTPUT TO MEMORY NO. 2 Me INSTRUCTION MRD MWR (HIGH MEMORY OUTPUT	ALLOWABLE ME MORY ACCESS	VALID D vaveforms	S11 FET (L1	OFF	EXECUTE (SI) MEMORY READ CYCLE ALID OUTPUT FETCH (SD)	FETCH (S0) MEMORY READ CYCLE VALID OUTPUT EXECUTE (S1) MEMORY READ

Fig. 13 - Machine-cycle timing waveforms (propagation delays not shown).



No. 5 Input-cycle timing waveforms.



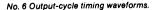


Fig. 13 - Machine-cycle timing waveforms (propagation delays not shown). Continued.

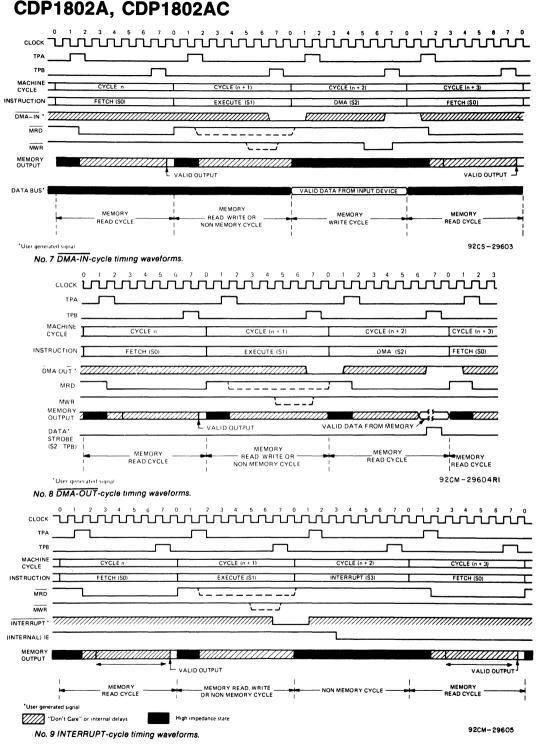


Fig. 13 - Machine-cycle timing waveforms (propagation delays not shown). Continued.